imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Power MOSFET 30 Amps, 60 Volts

N–Channel TO–220 and D²PAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

• Pb-Free Packages are Available

Typical Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	Vdc
Drain-to-Gate Voltage (R_{GS} = 10 M Ω)	V _{DGR}	60	Vdc
Gate–to–Source Voltage – Continuous – Non–Repetitive (t _p ≤10 ms)	V _{GS} V _{GS}	$\begin{array}{c} \pm20\\ \pm30 \end{array}$	Vdc
Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Continuous @ $T_A = 100^{\circ}C$ – Single Pulse ($t_p \le 10 \ \mu s$)	I _D I _D I _{DM}	27 15 80	Adc Apk
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	88.2 0.59	W W/°C
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to +175	°C
$ Single Pulse Drain-to-Source Avalanche \\ Energy - Starting T_J = 25^\circ C \\ (V_{DD} = 50 \mbox{ Vdc}, V_{GS} = 10 \mbox{ Vdc}, L = 0.3 \mbox{ mH} \\ I_{L(pk)} = 26 \mbox{ A}, V_{DS} = 60 \mbox{ Vdc}) $	E _{AS}	101	mJ
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.7	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8 in from case for 10 seconds	ΤL	260	°C

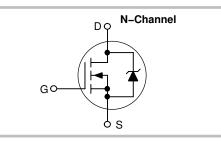
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

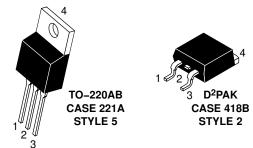


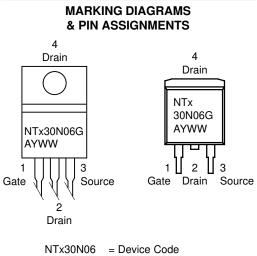
ON Semiconductor®

http://onsemi.com

30 AMPERES, 60 VOLTS R_{DS(on)} = 42 m Ω







NTx30N06	= Device Code
х	= B or P
А	= Assembly Location
Υ	= Year
WW	= Work Week
G	= Pb-Free Package

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ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown (V _{GS} = 0 Vdc, I _D = 250 μAd Temperature Coefficient (Posi	V _{(BR)DSS}	60 -	71.1 70		Vdc mV/°C	
$\label{eq:VDS} \begin{array}{l} \mbox{Zero Gate Voltage Drain Curre} \\ (V_{DS}=60 \mbox{ Vdc}, \mbox{ V}_{GS}=0 \mbox{ Vdc} \\ (V_{DS}=60 \mbox{ Vdc}, \mbox{ V}_{GS}=0 \mbox{ Vdc} \end{array}$	c)	I _{DSS}			1.0 10	μAdc
Gate-Body Leakage Current	$V_{GS} = \pm 20 \text{ Vdc}, V_{DS} = 0 \text{ Vdc})$	I _{GSS}	-	-	±100	nAdc
ON CHARACTERISTICS (Note	1)					
$\begin{array}{l} \mbox{Gate Threshold Voltage (Note} \\ \mbox{(V}_{DS} = V_{GS}, \mbox{ I}_{D} = 250 \ \mu \mbox{Adc}) \\ \mbox{Threshold Temperature Coefficients} \end{array}$,	V _{GS(th)}	2.0	3.05 7.3	4.0	Vdc mV/°C
Static Drain-to-Source On-R (V_{GS} = 10 Vdc, I _D = 15 Adc	. ,	R _{DS(on)}	-	35	42	mΩ
$ Static Drain-to-Source On-Vertex (V_{GS} = 10 Vdc, I_D = 30 Adc (V_{GS} = 10 Vdc, I_D = 15 Adc) $	V _{DS(on)}		1.1 0.98	1.5 -	Vdc	
Forward Transconductance (N	lote 1) (V _{DS} = 7.0 Vdc, I _D = 15 Adc)	g fs	-	16	-	mhos
OYNAMIC CHARACTERISTIC	3					
Input Capacitance		C _{iss}	-	850	1200	pF
Output Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{oss}	-	250	350	
Transfer Capacitance		C _{rss}	-	68	100	
SWITCHING CHARACTERIST	CS (Note 2)		_			
Turn-On Delay Time		t _{d(on)}	-	11	25	ns
Rise Time	$(V_{DD} = 30 \text{ Vdc}, I_D = 30 \text{ Adc},$	t _r	-	36	80	
Turn-Off Delay Time	V_{GS} = 10 Vdc, R_G = 9.1 Ω) (Note 1)	t _{d(off)}	-	24	50	
Fall Time		t _f	-	31	60	
Gate Charge		QT	-	23.4	46	nC
	(V _{DS} = 48 Vdc, I _D = 30 Adc, V _{GS} = 10 Vdc) (Note 1)	Q ₁	-	5.1	-]
		Q ₂	-	11	-	
SOURCE-DRAIN DIODE CHA	RACTERISTICS					_
Forward On–Voltage		V_{SD}		1.03 1.05	1.15 -	Vdc
Reverse Recovery Time	<i>"</i>	t _{rr}	-	52	-	ns
	(I _S = 30 Adc, V _{GS} = 0 Vdc, dI _S /dt = 100 A/μs) (Note 1)	t _a	-	38	-	
		+.		15		1

Reverse Recovery Stored Charge

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.

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0.094

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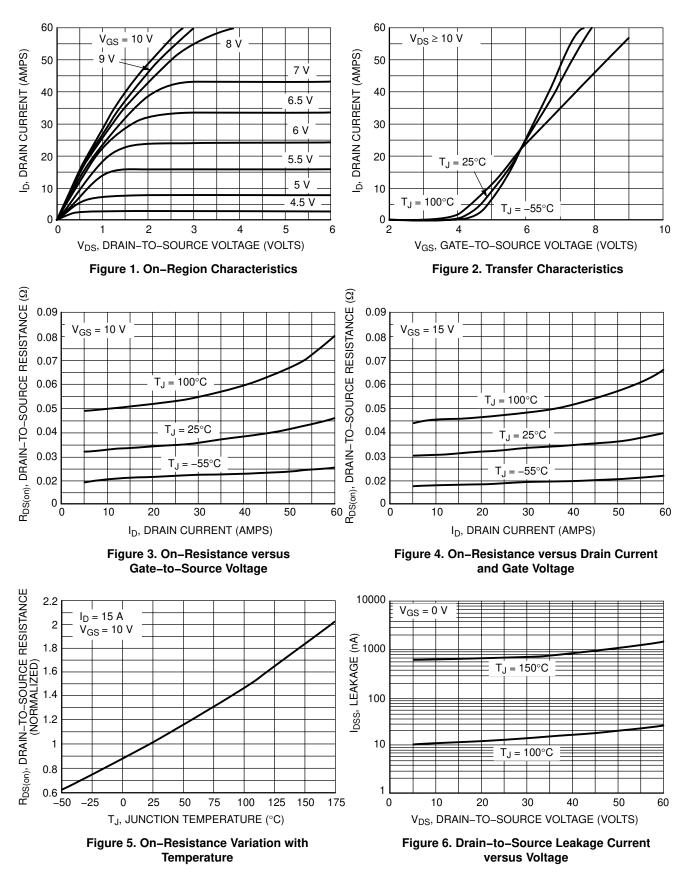
μC

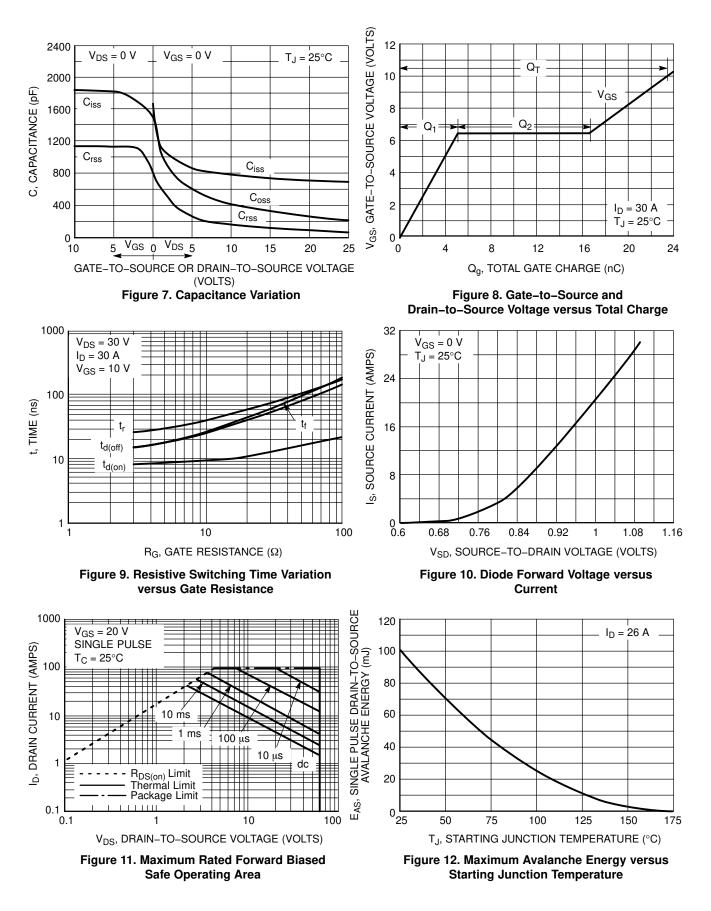
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t_b

 $\mathsf{Q}_{\mathsf{R}\mathsf{R}}$





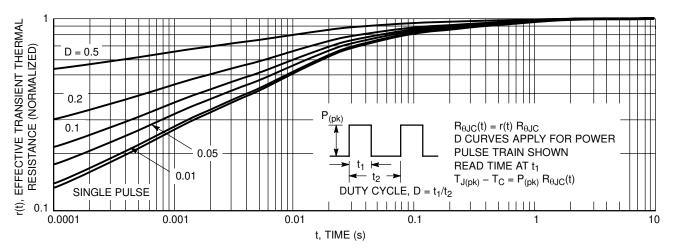


Figure 13. Thermal Response

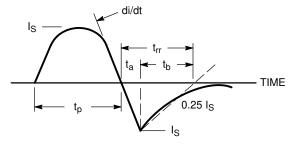


Figure 14. Diode Reverse Recovery Waveform

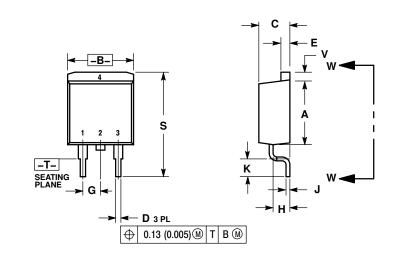
ORDERING INFORMATION

Device	Package	Shipping [†]
NTP30N06	TO-220AB	50 Units / Rail
NTB30N06	D ² PAK	50 Units / Rail
NTB30N06G	D ² PAK (Pb–Free)	50 Units / Rail
NTB30N06T4	D ² PAK	800 Units / Tape & Reel
NTB30N06T4G	D ² PAK (Pb–Free)	800 Units / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

D²PAK CASE 418B-04 ISSUE J



2.	DIME PER CON 418B	NSIONIN ANSI Y14 FROLLIN -01 THRI STANDA	I.5M, 198 G DIMEN U 418B-I	32. NSION: II 03 OBSC	NCH.	
		INC	HES	MILLIN	IETERS	
	DIM	MIN	MAX	MIN	MAX	
	Α	0.340	0.380	8.64	9.65	
	В	0.380	0.405	9.65	10.29	
	С	0.160	0.190	4.06	4.83	
	D	0.020	0.035	0.51	0.89	
	Е	0.045	0.055	1.14	1.40	
	F	0.310	0.350	7.87	8.89	
	G	0.100	BSC	2.54 BSC		
	н	0.080	0.110	2.03	2.79	
	J	0.018	0.025	0.46	0.64	
	к	0.090	0.110	2.29	2.79	
	L	0.052	0.072	1.32	1.83	
	М	0.280	0.320	7.11	8.13	
	Ν	0.197	REF	5.00	REF	
	Р	0.079 REF 2.00 REF				
	R	0.039	REF	0.99	REF	
	S	0.575	0.625	14.60	15.88	
	V	0.045	0.055	1.14	1.40	



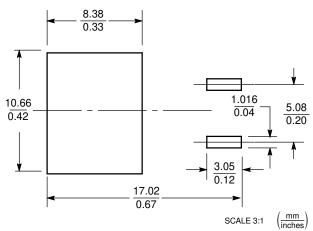




VARIABLE CONFIGURATION ZONE Ν R U -М М М VIEW W-W VIEW W-W

VIEW W-W

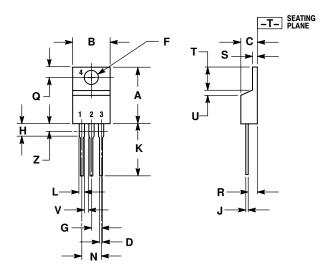
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AA**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2

CONTROLLING DIMENSION: INCH. DIMENSION Z DEFINES A ZONE WHERE ALL 3. BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
Κ	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
۷	0.045		1.15		
Ζ		0.080		2.04	

PIN 1 GATE DRAIN 2. 3. SOURCE 4. DRAIN

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